

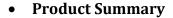
AP3410A 30V N-Channel Enhancement Mode MOSFET

• General Description

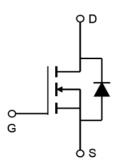
AP3410A combines advanced MOSFET technology with a low resistance package to provide extremely low $R_{DS(ON)}$. This device is most suitable to load-switch or PWM applications.

Applications

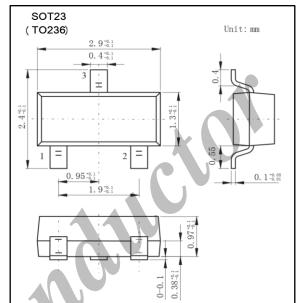
- DC/DC converter for portable devices
- Load switch



$V_{ extsf{DS}}$	30V
In (at $V_{GS} = 10V$)	5.8A
$R_{DS(ON)}$ (at $V_{GS} = 10V$)	< 28mΩ
$R_{DS(ON)}$ (at $V_{GS} = 4.5V$)	< 33mΩ
$R_{DS(ON)}$ (at $V_{GS} = 2.5V$)	< 42mΩ
$R_{DS(ON)}$ (at $V_{GS} = 1.8V$)	< 72mΩ











• Absolute Maximum Ratings Ta = 25°C

Parameter		Symbol	Rating	Unit	
Drain-Source Voltage		V_{DS}	30) V	
Gate-Source Voltage		V_{GS}	±12	V	
Continuous Drain Current	T _A =25°C	I_D	5.8		
	T _A =70°C		4.9	A	
Pulsed Drain Current *		I_{DM}	30	1	
Power Dissipation	T _A =25°C	D.	1.4	W	
	T _A =70°C	P_D	1		
The same I Decision of London to Applicate	t ≤ 10s	D	90		
Thermal Resistance. Junction- to-Ambient	Steady State	$R_{\theta JA}$	125	°C/W	
Thermal Resistance. Junction- to-Lead (Steady State)		$R_{ heta JL}$	60]	
Junction Temperature Storage Temperature Range		T _J	150	90	
		T_{STG}	-55 to 150	°C	

^{*} Repetitive rating, pulse width limited by junction temperature.

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• Electrical Characteristics Ta = 25°C

Parameter	Symbol	Test conditions	Min	Тур	Max	Unit
Drain-Source Breakdown Voltage	V_{DSS}	$I_D=250\mu A$, $V_{GS}=0V$	30			V
		V _{DS} =24V, V _{GS} =0V			1	.0
Zero Gate Voltage Drain Current	I_{DSS}	$V_{DS}=24V$, $V_{GS}=0V$, $T_{J}=55$ °C			5	μA
Gate-Body leakage current	I _{GSS}	$V_{DS}=0V$, $V_{GS}=\pm 12V$		_	±100	nA
Gate Threshold Voltage	V _{GS(th)}	$V_{DS}=V_{GS}$, $I_D=250\mu A$	0.5	K	1	V
Static Drain-Source On-Resistance		V_{GS} =10V, I_{D} =5.8A			28	mΩ
		$V_{GS}=10V, I_{D}=5.8A$ $T_{J}=125^{\circ}C$			39	
	R _{DS(ON)}	V_{GS} =4.5V, I_D =5A			33	
		V_{GS} =2.5V, I_D =4A	A B		42	
		V _{GS} =1.8V, I _D =3A			72	
On State Drain Current	$I_{D(ON)}$	V_{GS} =4.5V, V_{DS} =5V	30			A
Forward Transconductance	g_{FS}	V_{DS} =5V, I_D =3.6A	12	17		S
Input Capacitance	C_{iss}			767		
Output Capacitance	C_{oss}	V_{GS} =0V, V_{DS} =15V, f=1MHz		111		pF
Reverse Transfer Capacitance	C_{rss}			82		
Gate Resistance	Rg	$V_{GS}=0V$, $V_{DS}=0V$, $f=1MHz$		1.3		Ω
Total Gate Charge	Q_{g}			10		
Gate Source Charge	Q_{gs}	V_{GS} =4.5V, V_{DS} =15V, I_{D} =5.8A		1.2		nC
Gate Drain Charge	Q_{gd}			3.1		
Turn-On Delay Time	$t_{D(on)}$			5		
Turn-On Rise Time	$t_{\rm r}$	V_{GS} =10V, V_{DS} =15V,		5.5		na
Turn-Off Delay Time	$t_{D(off)}$	$R_L=2.7\Omega$, $R_{GEN}=6\Omega$		39		ns
Turn-Off Fall Time	t_{f}] [4.7		
Body Diode Reverse Recovery Time	t _{rr}	L-EA d./d-1004/ug		15		ns
Body Diode Reverse Recovery Charge	Q_{rr}	$I_F=5A$, $d_I/d_t=100A/\mu s$		7.1		nC
Maximum Body-Diode Continuous Current	I_S				2.5	A
Diode Forward Voltage	V_{SD}	$I_S=1A$, $V_{GS}=0V$			1	V

• Ordering Information

Ordering Part Number	Package	MOQ
AP3410A	SOT23 (TO236)	3,000 pcs / reel

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